# NSN 5962-01-100-9476

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View Online at https://aerobasegroup.com/nsn/5962-01-100-9476

#### **Body Length:**

Between 0.770 inches and 0.810 inches

#### Body Width:

Between 0.278 inches and 0.300 inches

#### **Body Height:**

Between 0.085 inches and 0.135 inches

#### **Maximum Power Dissipation Rating:**

794.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and monolithic and bipolar and expandable and programmable and 3-state output

#### **Inclosure Material:**

### Ceramic and glass

Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

10 input

#### **Terminal Surface Treatment:**

Gold

## Voltage Rating And Type Per Characteristic:

5.5 volts power source

## Memory Device Type:

Rom

## Memory Capacity:

Unknown

## **Precious Material And Location:**

Terminal surface gold

## **Precious Material:**

Gold

# Test Data Document:

98747-7823972 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

16 printed circuit

## Shelf Life:

N/a

### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

A458a0

